

IXFT14N100 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXFT14N100-DG

Manufacturer IXYS

Manufacturer Product Number IXFT14N100

Description MOSFET N-CH 1000V 14A TO268

Detailed Description N-Channel 1000 V 14A (Tc) 360W (Tc) Surface Moun

t TO-268AA



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFT14N100	IXYS
Series:	Product Status:
HiPerFET™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
1000 V	14A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	750mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 4mA	220 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	4500 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	360W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
TO-268AA	TO-268-3, D ³ Pak (2 Leads + Tab), TO-268AA
Base Product Number:	
IXFT14	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:	
1 (Unlimited)	EAR99	
HTSUS:		
8541.29.0095		



OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935